/ Descriptions

TO-220 N

N-CHANNEL MOSFET in a TO-220 Plastic Package.

/ Features

V_{DS}=40V I_D=177A V_{GS}=±20V

$R_{DS(on)}$@10V，3.0mΩ(Type.2.5mΩ)

$R_{DS(on)}$@4.5V，5.0mΩ(Type.3.5mΩ)

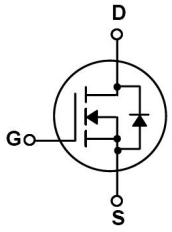
HF Product.

/ Applications

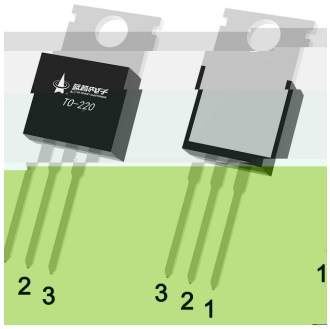
DC/DC

DC Motor Driver,Synchronous Rectification in DC/DC Converters.

/ Equivalent Circuit



/ Pinning



PIN1 G PIN 2 4 D PIN 3 S

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings(Ta=25)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DSS}	40	V
Drain Current		I_D(Tc=25)	177	A
Pulsed Drain Current		I_{DM}	560	A
Gate-Source Voltage		V_{GS}	±20	V
Single Pulsed Avalanche Energy L=0.5mH		E_{AS}	435	mJ
Avalanche Current		I_{AS}	33	A
Total Power Dissipation		P_D(Tc=25)	170	W
Junction and Storage Temperature Range		T_J,T_{STG}	-55 to 150	
Thermal Resistance-Junction to Ambient	t ≤ 10s	$R_{\theta JA}$	15	/W
	Steady-State		60	
Thermal Resistance-Junction to Case	Steady-State	$R_{\theta JC}$	0.74	

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V I_D=250εA	40	47		V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=40V V_{GS}=0V			1	εA
Gate-Body Leakage Current Forward	I_{GSS}	V_{GS}=±20V V_{DS}=0V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS} I_D=250εA	1	1.7	3	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS}=10V I_D=20A		2.5	3	mq
		V_{GS}=4.5V I_D=10A		3.5	5	
Forward On Voltage	V_{SD}	V_{GS}=0V I_S=1A			1.2	V
Gate resistance	R_g	V_{GS}=0V V_{DS}=0V, f=1MHz		1.3		q
Input Capacitance	C_{iss}	V_{DS}=25V V_{GS}=0V f=1MHz		9600		pF
Output Capacitance	C_{oss}			740		
Reverse Transfer Capacitance	C_{rss}			650		
Total Gate Charge	$Q_{g(10V)}$	V_{GS}=10V, V_{DS}=20V, I_D=20A		51		nC
Total Gate Charge	$Q_{g(4.5V)}$			23		
Gate Source Charge	Q_{gs}			13.2		
Gate Drain Charge	Q_{gd}			3.1		

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	V_{GS}=10V V_{DS}=20V R_L=1Ω R_{GEN}=3Ω		11		ns
Turn-On Rise Time	t_r			11		
Turn-Off Delay Time	$t_{d(off)}$			40		
Turn-Off Fall Time	t_f			10		

/ Electrical Characteristic Curve

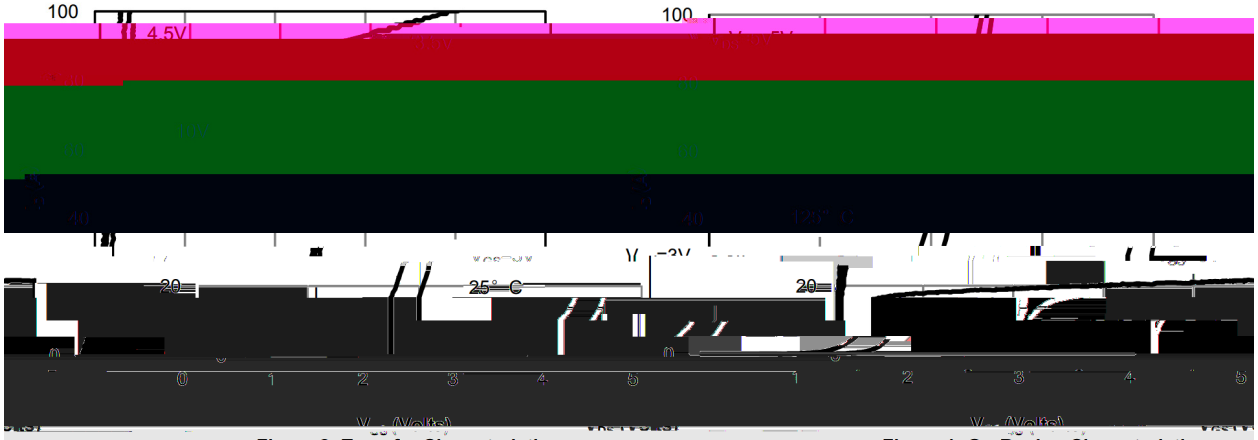
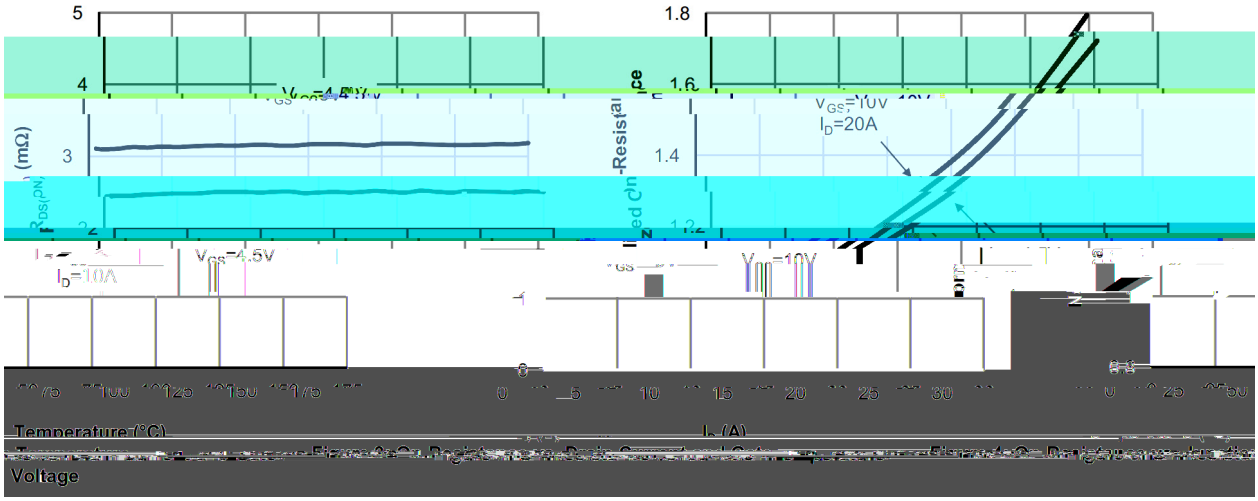
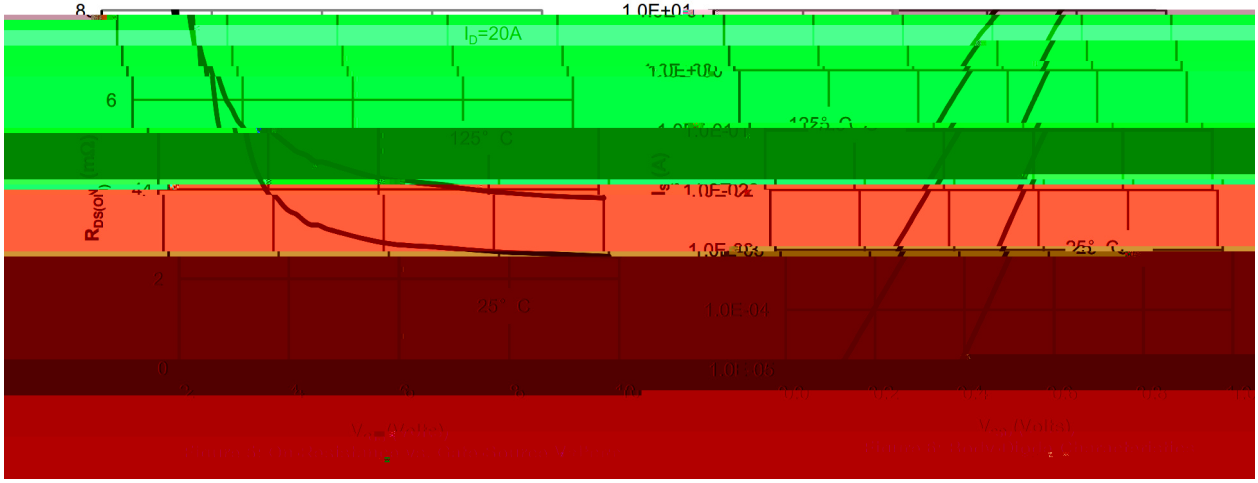


Figure 2: Transfer Characteristics

Figure 1: On-Region Characteristics





/ Electrical Characteristic Curve

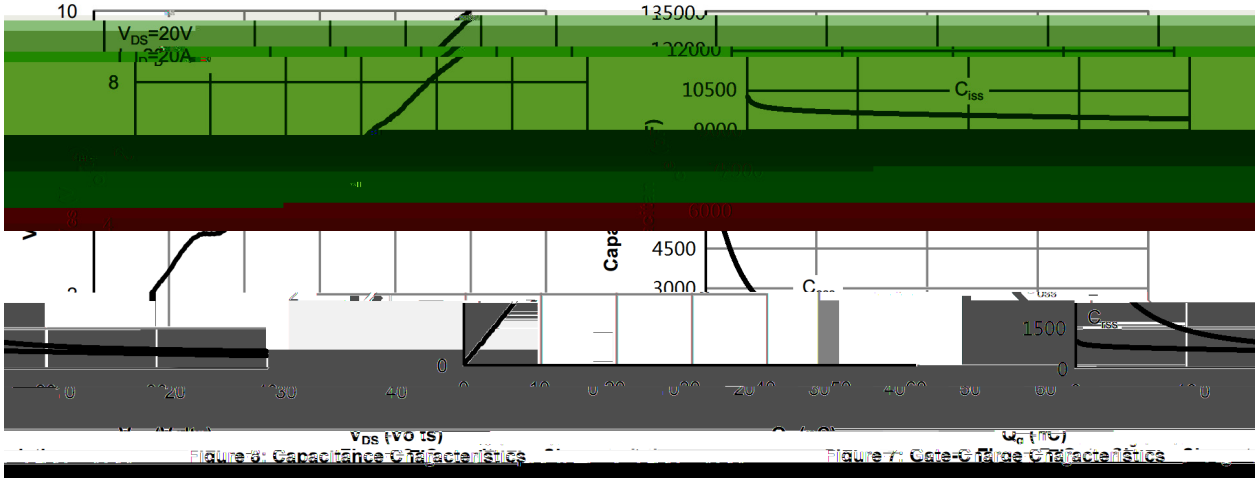
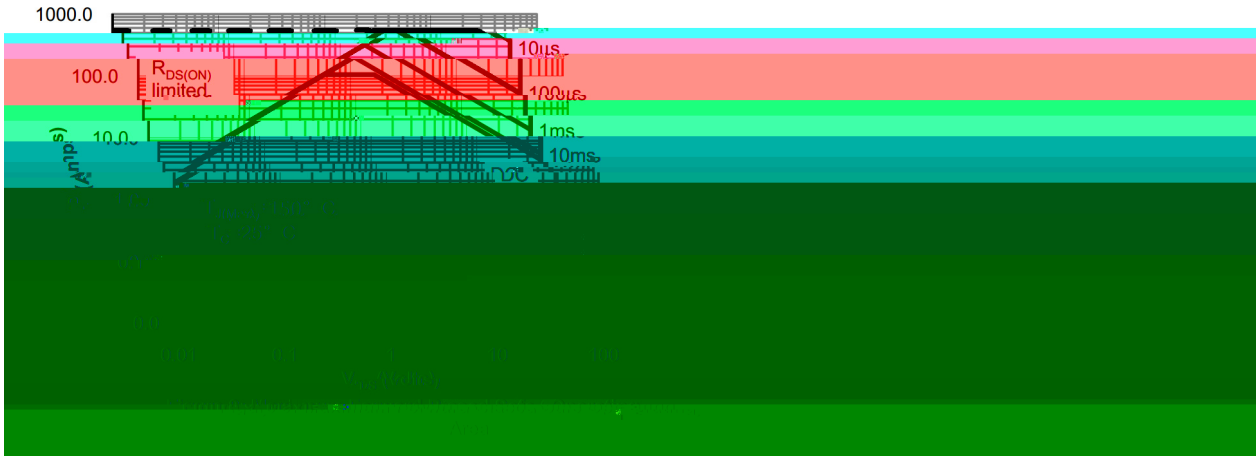


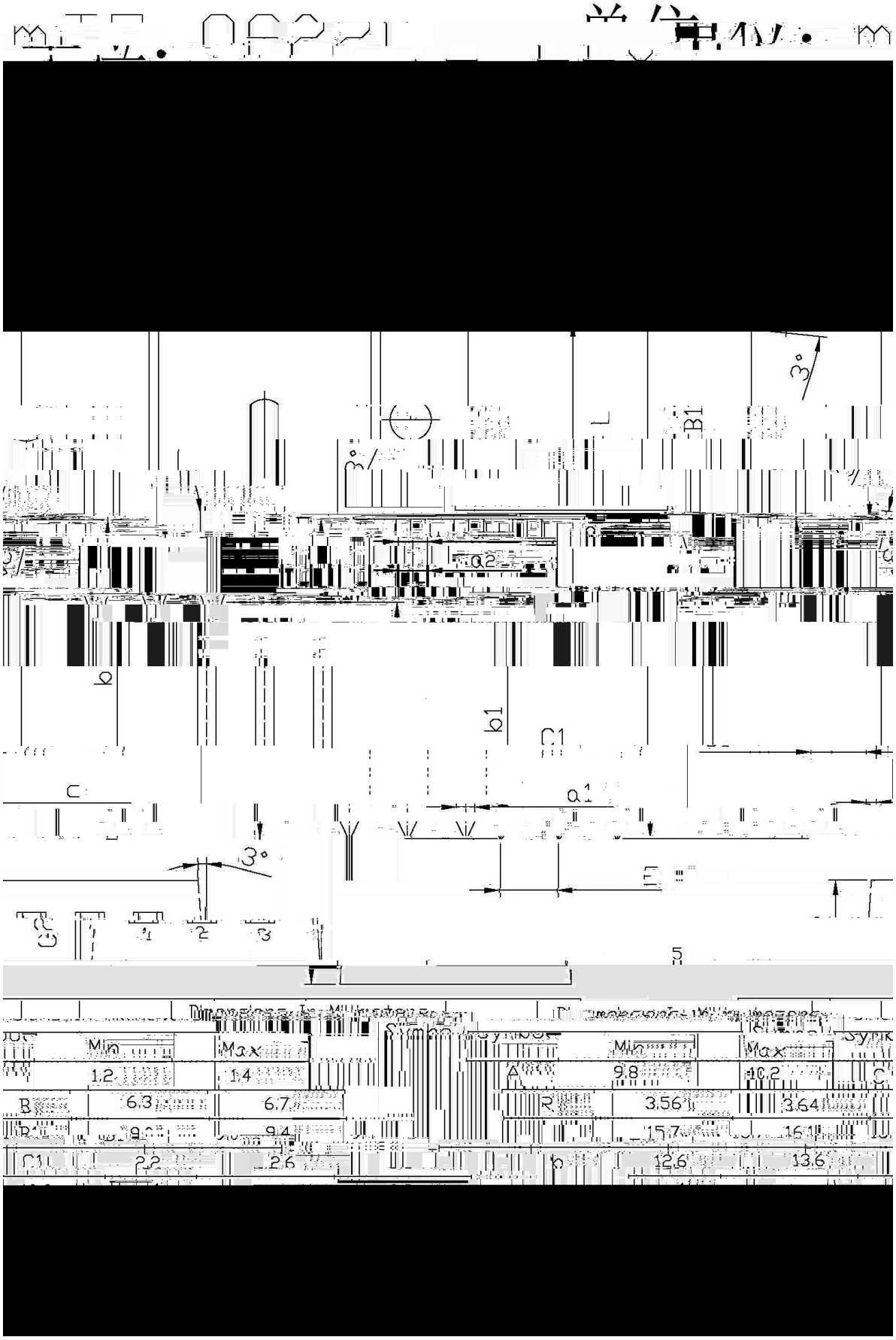
Figure 6: Capacitance Characteristics

Figure 7: Gate-Charge Characteristics

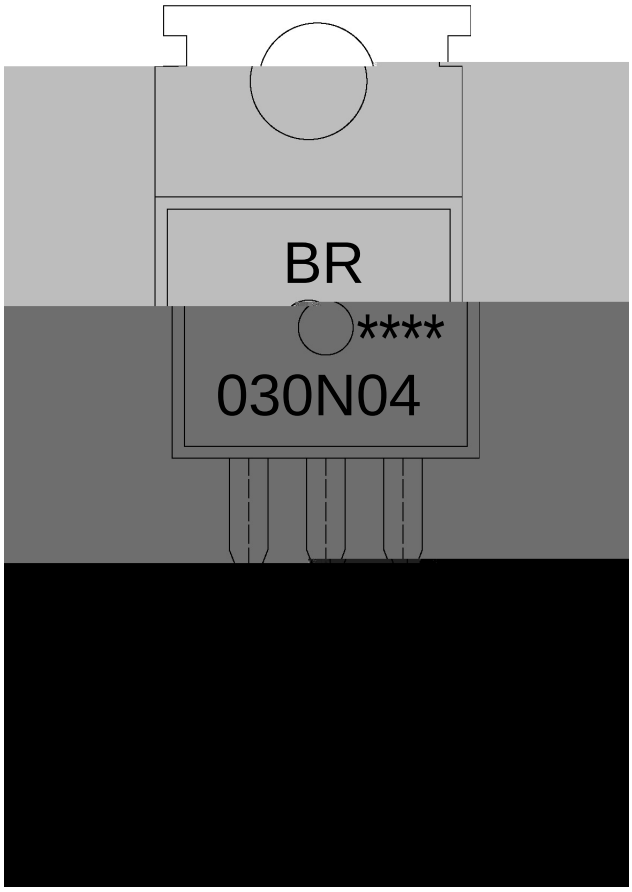




/ Package Dimensions



/ Marking Instructions



BR

030N04

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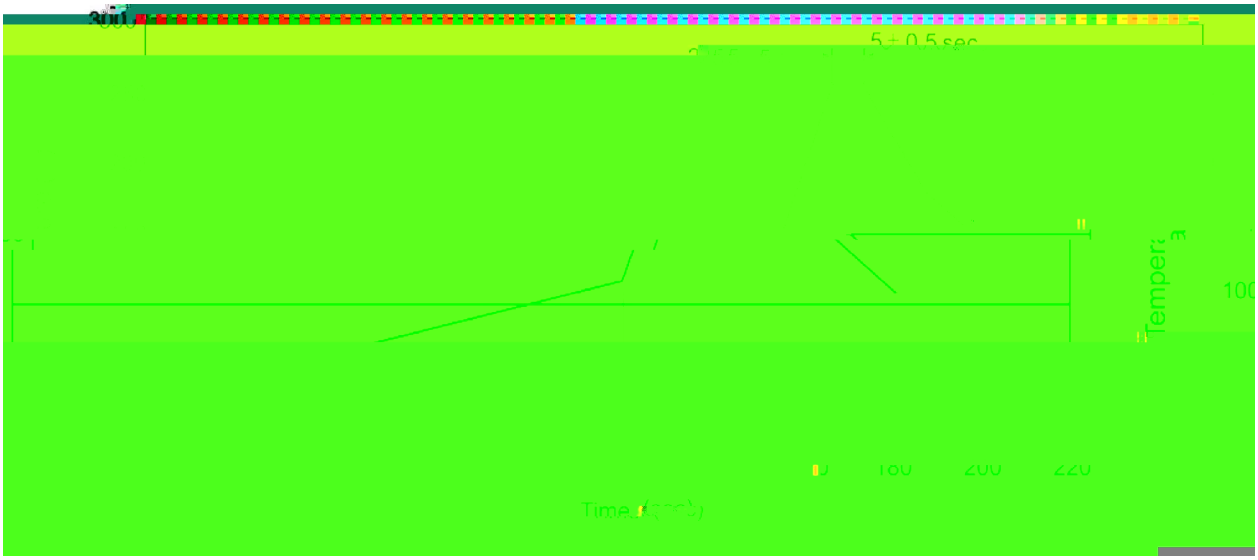
Note:

BR:	Company Code
030N04:	Product Type
****:	Lot No. Code, code change with Lot No

( ) / Temperature Profile for Dip Soldering(Pb-Free)



				Note:
1	25	150	60 90sec;	1.Preheating:25~150 , Time:60~90sec.
2	255±5		5±0.5sec;	2.Peak Temp.:255±5 , Duration:5±0.5s
3		10	/sec.	3. Cooling Speed: 2~10 /sec.

/ Res ce to Sol st Conditions

0±5 0±1 sec. T :270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Packag ype	Units 0e							Box
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box
TO-220/F	200	10	2,000	5	10,000	135×190	237×172×102	560×245×195

Pack